



### DN0150ALP4 / DN0150BLP4

### NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

### **Features**

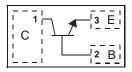
- Epitaxial Die Construction
- Ultra-Small Leadless Surface Mount Package
- Ultra Low Profile (0.4mm max)
- Complementary PNP Type Available (DP0150ALP4 / DP0150BLP4)
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q 101 Standards for High Reliability



**Bottom View** 

### **Mechanical Data**

- Case: DFN1006H4-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections Indicator: Collector Dot
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Ordering Information: See Page 3
- Marking Information: See Page 3
- Weight: 0.0008 grams (approximate)



Top View Device Schematic

### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                 | Symbol           | Value | Unit |
|--------------------------------|------------------|-------|------|
| Collector-Base Voltage         | $V_{CBO}$        | 60    | V    |
| Collector-Emitter Voltage      | $V_{CEO}$        | 50    | V    |
| Emitter-Base Voltage           | V <sub>EBO</sub> | 5     | V    |
| Collector Current – Continuous | Ic               | 100   | mA   |
| Peak Pulse Collector Current   | I <sub>CM</sub>  | 200   | mA   |
| Base Current                   | I <sub>B</sub>   | 30    | mA   |

### **Thermal Characteristics**

| Characteristic                                   | Symbol                            | Value       | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 3)                       | P <sub>D</sub>                    | 450         | mW   |
| Thermal Resistance, Junction to Ambient (Note 3) | $R_{	hetaJA}$                     | 278         | °C/W |
| Operating and Storage Temperature Range          | T <sub>J</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

### **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

| Characteristic                       |           | Symbol               | Min | Тур  | Max  | Unit    | Test Condition                            |
|--------------------------------------|-----------|----------------------|-----|------|------|---------|---|
| OFF CHARACTERISTICS                  |           |                      |     |      |      |         |   |
| Collector-Base Breakdown Voltage     |           | V(BR)CBO             | 60  | _    | _    | V       | $I_C = 10 \mu A, I_E = 0$                 |
| Collector-Emitter Breakdown Voltage  | (Note 4)  | V(BR)CEO             | 50  | _    | _    | V       | $I_C = 1 \text{mA}, I_B = 0$              |
| Emitter-Base Breakdown Voltage       |           | V( <sub>BR)EBO</sub> | 5   | _    | _    | V       | $I_E = 10 \mu A, I_C = 0$                 |
| Collector Cut-Off Current            |           | I <sub>CBO</sub>     | _   | _    | 0.1  | μΑ      | $V_{CB} = 60V, I_{E} = 0$                 |
| Emitter Cut-Off Current              |           | I <sub>EBO</sub>     | _   | _    | 0.1  | μΑ      | $V_{EB} = 5V, I_{C} = 0$                  |
| ON CHARACTERISTICS (Note 4)          |           |                      |     |      |      |         |   |
| Collector-Emitter Saturation Voltage |           | V <sub>CE(SAT)</sub> | _   | 0.10 | 0.25 | V       | $I_C = 100 \text{mA}, I_B = 10 \text{mA}$ |
| DC Current Gain                      | DN0150ADJ |                      | 120 | _    | 240  |         | $V_{CF} = 6V$ , $I_{C} = 2mA$             |
|                                      | DN0150BDJ | h <sub>FE</sub>      | 200 |      | 400  |         | VCE = OV, IC = ZIIIA                      |
| SMALL SIGNAL CHARACTERISTICS         |           |                      |     |      |      |         |   |
| Transition Frequency                 |           | f⊤                   | 60  |      |      | MHz     | $V_{CE} = 10V$ , $I_E = -1mA$             |
| Transition requeitey                 |           | 11                   | 00  |      |      | IVII IZ | f = 30MHz                                 |
| Output Capactiance                   |           | C <sub>ob</sub>      | _   | 1.3  | _    | pF      | $V_{CB} = 10V, I_E = 0,$<br>f = 1MHz      |

Notes:

- 1. No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
- 3. Device mounted on FR-4 PCB with minimum recommended pad layout.
- 4. Measured under pulsed conditions. Pulse width =  $300\mu s$ . Duty cycle  $\leq 2\%$

## **DODES**

### DN0150ALP4 / DN0150BLP4

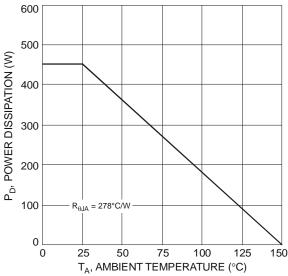
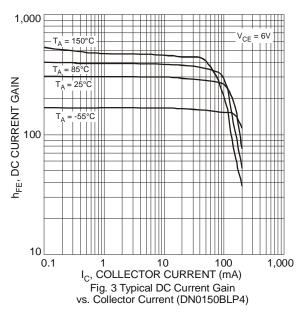
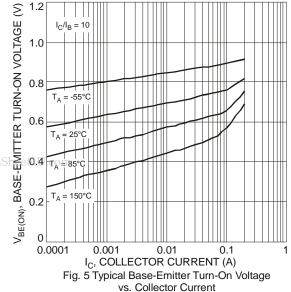


Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)





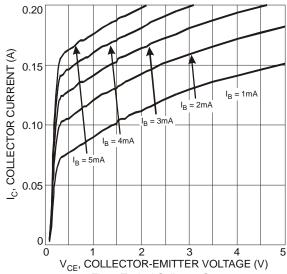


Fig. 2 Typical Collector Current vs. Collector-Emitter Voltage (DN0150BLP4)

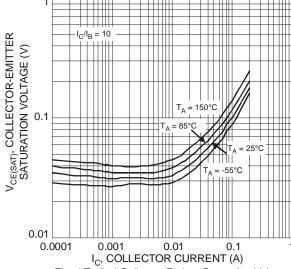


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

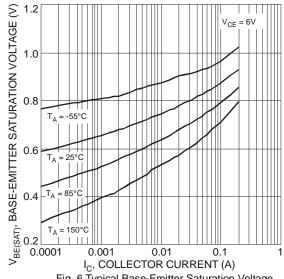
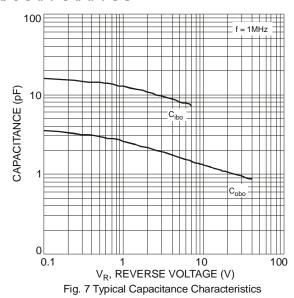


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

# **DODES**

### DN0150ALP4 / DN0150BLP4



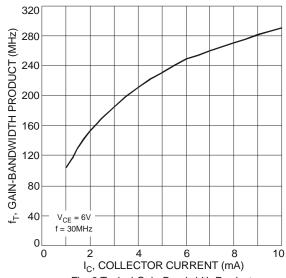


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

## Ordering Information (Note 5)

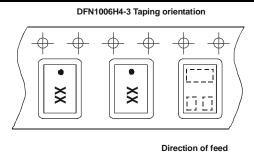
| Ī | Device       | Packaging   | Shipping         |
|---|--------------|-------------|------------------|
|   | DN0150ALP4-7 | DFN1006H4-3 | 3000/Tape & Reel |
|   | DN0150BLP4-7 | DFN1006H4-3 | 3000/Tape & Reel |

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

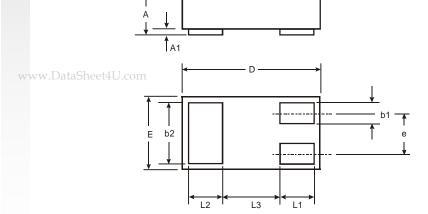
## **Marking Information**

• xx

xx= Product Type Marking Code: T3 = DN0150ALP4 T4 = DN0150BLP4 Dot Denotes Collector Side



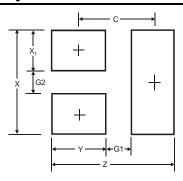
## **Package Outline Dimensions**



| DFN1006H4-3          |      |       |      |  |
|----------------------|------|-------|------|--|
| Dim                  | Min  | Max   | Тур  |  |
| A                    |      | 0.40  | _    |  |
| A1                   | 0    | 0.05  | 0.02 |  |
| b1                   | 0.10 | 0.20  | 0.15 |  |
| b2                   | 0.45 | 0.55  | 0.50 |  |
| ם                    | 0.95 | 1.075 | 1.00 |  |
| Е                    | 0.55 | 0.675 | 0.60 |  |
| e                    |      | _     | 0.35 |  |
| L1                   | 0.20 | 0.30  | 0.25 |  |
| L2                   | 0.20 | 0.30  | 0.25 |  |
| L3                   |      | _     | 0.40 |  |
| All Dimensions in mm |      |       |      |  |



### Suggested Pad Layout



| Dimensions | Value (in mm) |
|------------|---------------|
| Z          | 1.1           |
| G1         | 0.3           |
| G2         | 0.2           |
| Х          | 0.7           |
| X1         | 0.25          |
| Υ          | 0.4           |
| С          | 0.7           |

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